

**CONTACTLESS CHANNEL WRITE/ERASE FLASH MEMORY CELL AND ITS
FABRICATION METHOD**

Appl. No.	:	10/065,189	Confirmation No.	6308
Applicant	:	Ching-Hsiang Hsu, Ching-Sung Yang		
Filed	:	September 25, 2002	RECEIVED	
TC/A.U.	:	2818	CENTRAL FAX CENTER	
Examiner	:	David Vu	NOV 23 2004	
Docket No.	:	EMEP0007USA1		
Customer No.	:	27765		

Commissioner for Patents
P.O. Box 1450
Alexandria VA 22313-1450

AMENDMENT

Sir:

- 5 In response to the Office action of October 27, 2004, please amend the above-identified application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page2 of this paper.

Remarks/Arguments begin on page 4 of this paper.

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